NSN 5961-01-243-3965

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View Online at https://aerobasegroup.com/nsn/5961-01-243-3965 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.250 inches and 0.450 inches Overall Width: 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 450.0 collector to emitter voltage, dc with specified circuit between base and emitter **Current Rating Per Characteristic:** 15.00 amperes source cutoff current **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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